Photocouplers
CNY17-1-V thru CNY17-4-V SERIES

1. DESCRIPTION

1.1 Features

- Current transfer ratio (CTR : MIN. 40% at I_F = 10mA, V_{CE} = 5V)
- High collector-emitter voltage
  V_{CEO} = 70V
- High input-output isolation voltage
  Viso = 5,000Vrms
- Response time (tr : TYP. 5μs at VCE = 10V, IC = 2mA, RL = 100Ω)
- Dual-in-line package :
  CNY17-1-V, CNY17-2-V, CNY17-3-V, CNY17-4-V
- Wide lead spacing package :
  CNY17-1M-V, CNY17-2M-V, CNY17-3M-V, CNY17-4M-V
- Surface mounting package :
  CNY17-1S-V, CNY17-2S-V, CNY17-3S-V, CNY17-4S-V
- Tape and reel packaging :
  CNY17-1S-TA-V, CNY17-2S-TA-V, CNY17-3S-TA-V, CNY17-4S-TA-V
  CNY17-1S-TA1-V, CNY17-2S-TA1-V, CNY17-3S-TA1-V, CNY17-4S-TA1-V
- Safety approval
  * UL approved (No. E113898)
  * TUV approved (No. R9653630)
  * CSA approved (No. CA91533-1)
  * FIMKO approved (No. 193422-01)
  * VDE approved (No. 40015248)
  * BSI approved (No. 9018-9)
  * CQC approved (No.CQC11001061921-2)
- Creepage distance > 8.0 mm ; Clearance > 8.0 mm
- The relevant models are the models Approved by VDE according to DIN EN 60747-5-5

  Approved Model No.: CNY17-1-V, CNY17-2-V, CNY17-3-V, CNY17-4-V
  CNY17-1M-V, CNY17-2M-V, CNY17-3M-V, CNY17-4M-V
  CNY17-1S-V, CNY17-2S-V, CNY17-3S-V, CNY17-4S-V
  CNY17-1S-TA-V, CNY17-2S-TA-V, CNY17-3S-TA-V, CNY17-4S-TA-V
  CNY17-1S-TA1-V, CNY17-2S-TA1-V, CNY17-3S-TA1-V, CNY17-4S-TA1-V

  VDE approved No.: 40015248 (According to the specification DIN EN 60747-5-5)
- Operating isolation voltage VIORM : 850V (Peak)
- Transient voltage VTR : 6000V (Peak)
- Pollution : 2 (According to VDE 0110-1 : 1997-04)
- Clearances distance (Between input and output) : 7.0mm (MIN.)
- Creepage distance (Between input and output) : 7.0mm (MIN.)
- Isolation thickness between input and output : 0.4mm (MIN.)

- Safety limit values Current (Isi) : 400mA (Diode side)

  Power (Psi) : 700mW (Phototransistor side)

  Temperature(Tsi) : 175°C

  In order to keep safety electric isolation of photocoupler, please set the protective

  circuit to keep within safety limit values when the actual application equipment troubled.

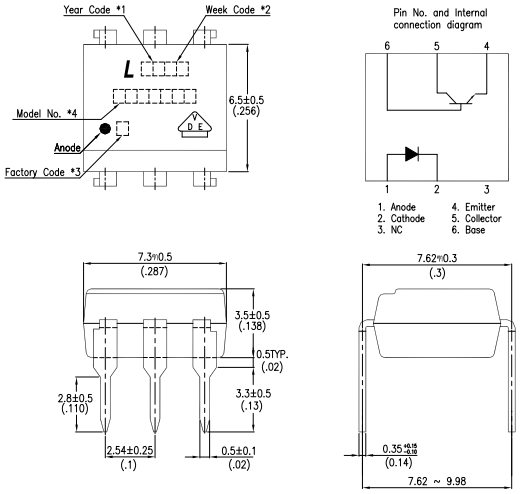
- Indication of VDE approval prints " " on sleeve package.
- RoHS Compliance
  All materials be used in device are followed EU RoHS directive (No.2002/95/EC).
- ESD pass HBM 8000V/MM2000V
- MSL class1

1.2 Applications

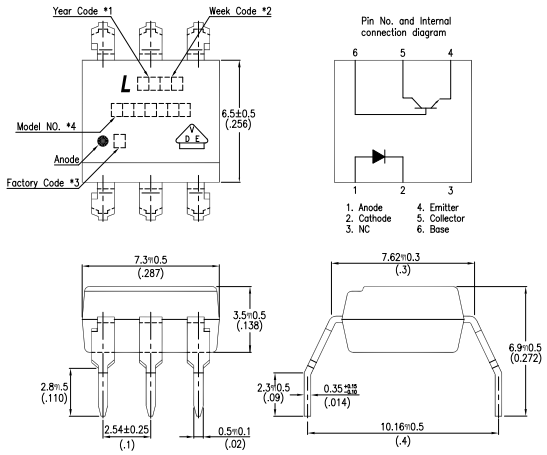
- Power Supply regulators
- Digital logic inputs
- Microprocessor inputs
- Appliance Sensor Systems
- Industrial Controls

2. PACKAGE DIMENSIONS

2.1 CNY17-1-V, CNY17-2-V, CNY17-3-V, CNY17-4-V :



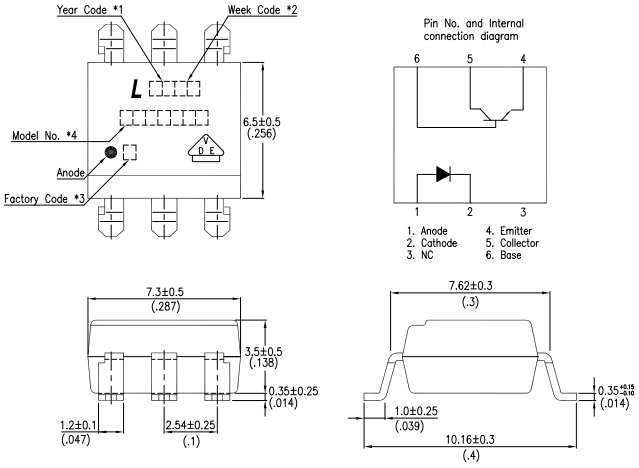
2.2 CNY17-1M-V, CNY17-2M-V, CNY17-3M-V, CNY17-4M-V :



Notes :

1. Year date code.
2. 2-digit work week.
3. Factory identification mark shall be marked (Y: Thailand, W: China-CZ, X: China-TJ).
4. Model No.: CNY17-1, CNY17-2, CNY17-3, CNY17-4

2.3 CNY17-1S-V, CNY17-2S-V, CNY17-3S-V, CNY17-4S-V :

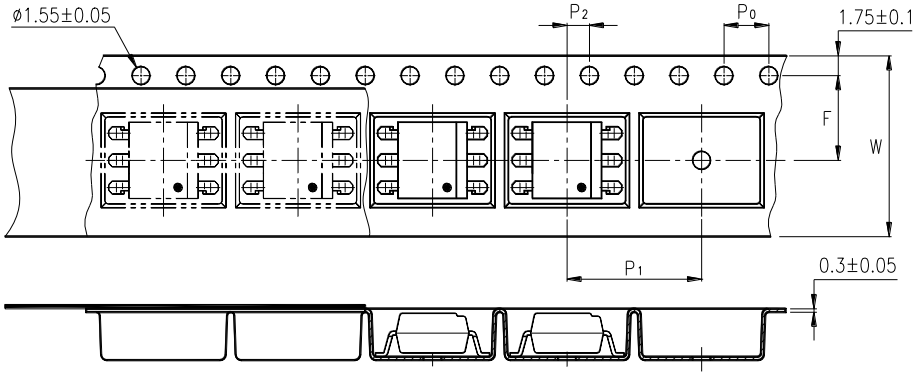


Notes :

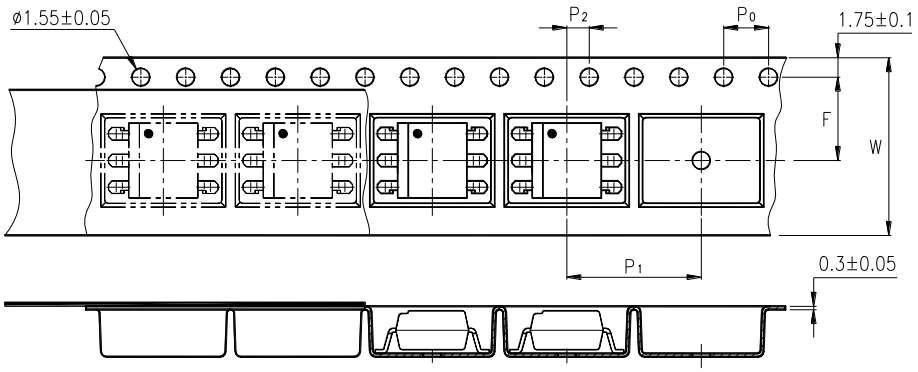
1. Year date code.
2. 2-digit work week.
3. Factory identification mark shall be marked (Y: Thailand, W: China-CZ, X: China-TJ).
4. Model No.: CNY17-1, CNY17-2, CNY17-3, CNY17-4

2. TAPING DIMENSIONS

CNY17-1S-TA-V, CNY17-2S-TA-V, CNY17-3S-TA-V, CNY17-4S-TA-V :



CNY17-1S-TA1-V, CNY17-2S-TA1-V, CNY17-3S-TA1-V, CNY17-4S-TA1-V :



Description	Symbol	Dimension in mm (inch)
Tape wide	W	16±0.3 (0.63)
Pitch of sprocket holes	P_0	4±0.1 (0.15)
Distance of compartment	F	7.5±0.1 (0.295)
	P_2	2±0.1 (0.079)
Distance of compartment to compartment	P_1	12±0.1 (0.472)

4. RATING AND CHARACTERISTICS

4.1 Absolute Maximum Ratings at Ta=25°C

Parameter		Symbol	Rating	Unit
Input	Forward Current	I_F	60	mA
	Reverse Voltage	V_R	6	V
	Power Dissipation	P	100	mW
Output	Collector - Emitter Voltage	V_{CEO}	70	V
	Emitter - Collector Voltage	V_{ECO}	7	V
	Collector - Base Voltage	V_{CBO}	70	V
	Collector Current	I_C	150	mA
	Collector Power Dissipation	P_C	150	mW
Total Power Dissipation		P_{tot}	250	mW
*1 Isolation Voltage		V_{iso}	5000	V_{rms}
Operating Temperature		T_{opr}	-55 ~ +100	°C
Storage Temperature		T_{stg}	-55 ~ +150	°C
*2 Soldering Temperature		T_{sol}	260	°C

*1. AC For 1 Minute, R.H. = 40 ~ 60%

Isolation voltage shall be measured using the following method.

(1) Short between anode and cathode on the primary side and between collector and emitter on the secondary side.

(2) The isolation voltage tester with zero-cross circuit shall be used.

(3) The waveform of applied voltage shall be a sine wave.

*2. For 10 Seconds

4.2 ELECTRICAL OPTICAL CHARACTERISTICS at Ta=25°C

PARAMETER			SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
INPUT	Forward Voltage		VF	—	1.45	1.65	V	IF=60mA
	Reverse Current		IR	—	—	10	μA	VR=6V
	Terminal Capacitance		Ct	—	—	100	pF	V=0, f=1KHz
OUTPUT	Collector Dark Current		ICEO	—	—	50	nA	VCE=10V, IF=0
	Collector-Emitter Breakdown Voltage		BVCEO	70	—	—	V	IC=0.1mA IF=0
	Emitter-Collector Breakdown Voltage		BVECO	7	—	—	V	IE=10μA IF=0
	Collector-Base Breakdown Voltage		BVCBO	70	—	—	V	IC=0.1mA IF=0
TRANSFER CHARACTERISTICS	*Transfer Ratio Current	CNY17-1	CTR	40	—	80	%	IF=10mA VCE=5V
		CNY17-2		63		125		
		CNY17-3		100		200		
		CNY17-4		160	—	320		
	Collector-Emitter Saturation Voltage		VCE(sat)	—	—	0.3	V	IF=10mA IC=2.5mA
	Isolation Resistance		Riso	100	—	—	GΩ	DC500V 40 ~ 60% R.H.
	Floating Capacitance		Cf	—	—	2	pF	V=0, f=1MHz
	Response Time (Rise)		tr	—	5	10	μs	VCE=10V, IC=2mA RL=100Ω
	Response Time (Fall)		tf	—	5	10	μs	

$$*\text{CTR} = \frac{I_C}{I_F} \times 100\%$$

4.3 ISOLATION SPECIFICATION ACCORDING TO VDE

Parameter		Symbol	Conditions	Rating	Unit	Remark
Class of environmental test		-	DIN IEC68	55/100/21	-	
Pollution		-	DIN VDE0110	2	-	
Maximum Operating Isolation Voltage		V_{IORM}	-	850	V_{PEAK}	
Partial Discharge Test Voltage (Between Input and Output)	Diagram 1	Vpr	tp=60s, qc<5pC	1275	V_{PEAK}	Refer to the Diagram 1, 2
	Diagram 2		tp=1s, qc<5pC	1594	V_{PEAK}	
Maximum Over-voltage		$V_{INITIAL}$	t_{INI} = 10s	6000	V_{PEAK}	
Safety Maximum Ratings						Refer to the Figure 1, 3
1) Case Temperature		Tsi	I_F = 0, Pc = 0	175	°C	
2) Input Current		Isi	Pc=0	400	mA	
3) Electric Power (Output or Total Power Issipation)		Psi	-	700	mW	
Isolation Resistance (Test Voltage Between Input and Output : DC500V)		R_{ISO}	Ta=Tsi	MIN.10^9	Ω	
			Ta=Topr(MAX.)	MIN.10^{11}		
			Ta=25 °C	MIN.10^{12}		

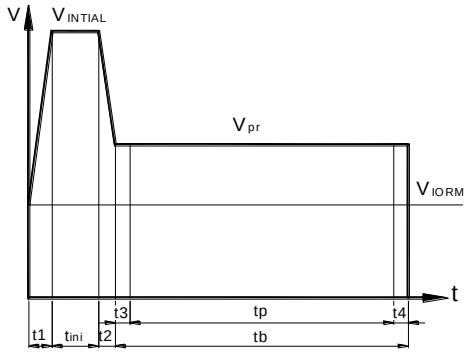
Precautions in performing isolation test

* Partial discharge test methods shall be the ones according to the specifications of DIN EN 60747-5-5

* Please don't carry out isolation test (Viso) over $V_{INITIAL}$,This product deteriorates isolation characteristics by partial discharge due to applying high voltage (ex. $V_{INITIAL}$). And there is possibility that this product occurs partial discharge in operating isolation voltage (V_{IORM})

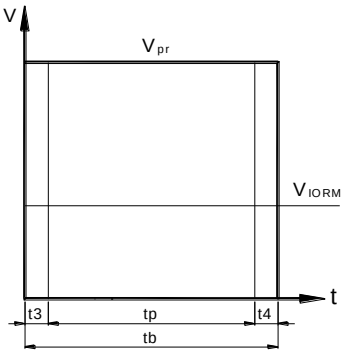
4.4 PARTIAL DISCHARGE TEST METHOD

Method (A) for type testing and random testing.



t1, t2 = 1 to 10s
t3, t4 = 1s
tp (Partial Discharge Measuring Time)= 60s
tb = 62s
tini = 10s

Method (B) for routine testing.



t3, t4 = 0.1s
tp (Partial Discharge Measuring Time)= 1s
tb = 1.2s

The partial discharge level shall not exceed 5 pc during the partial discharge measuring time interval t_p under the test conditions shown above.

5. CHARACTERISTICS CURVES

Fig.1 Forward Current vs. Ambient Temperature

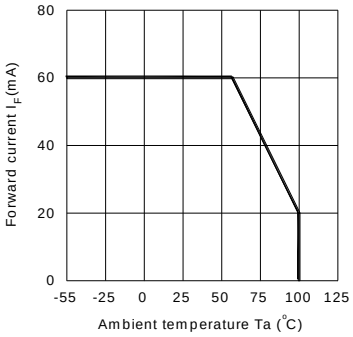


Fig.2 Collector Power Dissipation vs. Ambient Temperature

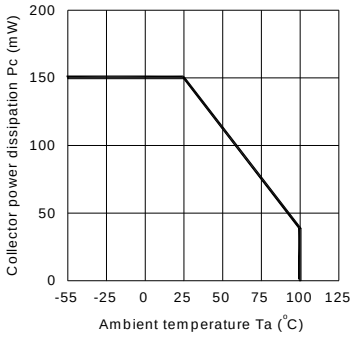


Fig.3 Collector-emitter Saturation Voltage vs. Forward Current

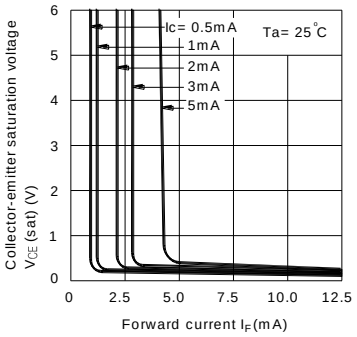


Fig.4 Forward Current vs. Forward Voltage

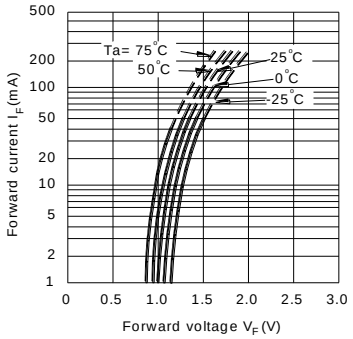


Fig.5 Current Transfer Ratio vs. Forward Current

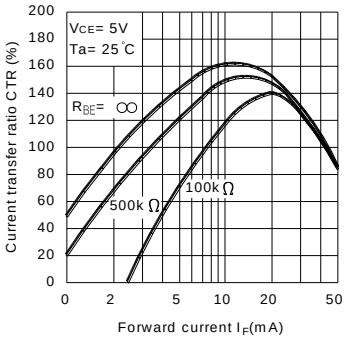


Fig.6 Collector Current vs. Collector-emitter Voltage

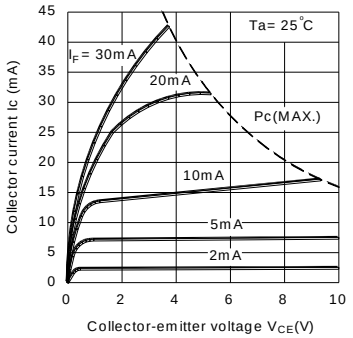


Fig.7 Relative Current Transfer Ratio vs. Ambient Temperature

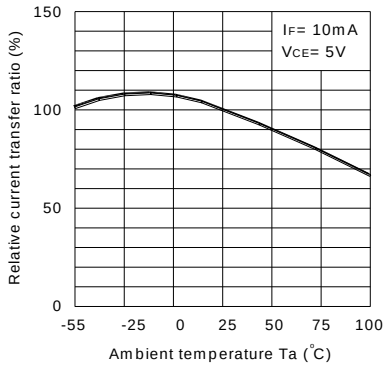


Fig.8 Collector-emitter Saturation Voltage vs. Ambient Temperature

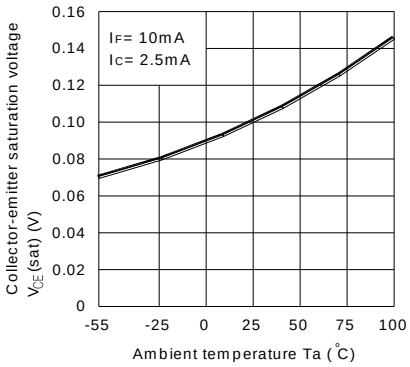


Fig.9 Collector Dark Current vs. Ambient Temperature

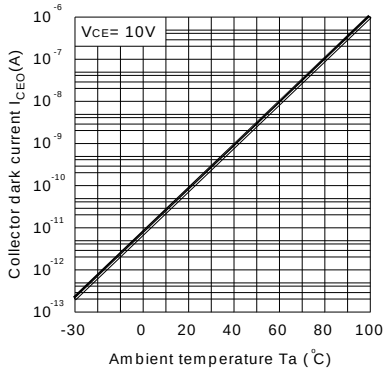


Fig.10 Response Time vs. Load Resistance

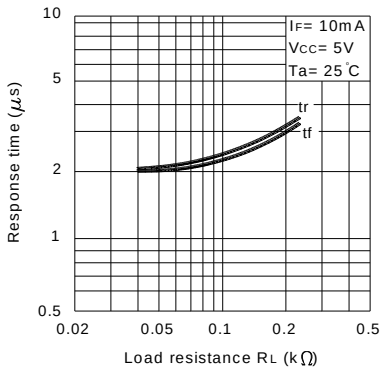
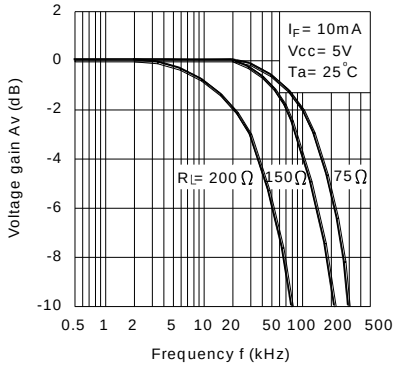
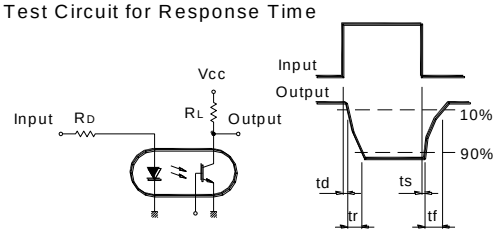


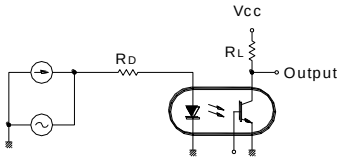
Fig.11 Frequency Response



Test Circuit for Response Time



Test Circuit for Frequency Response

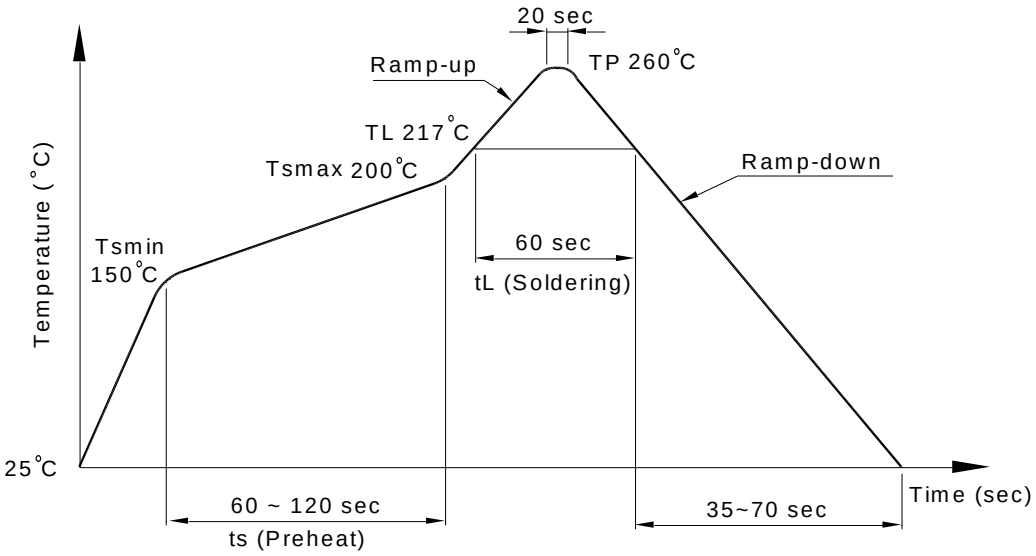


6. TEMPERATURE PROFILE OF SOLDERING

6.1 IR Reflow soldering (JEDEC-STD-020C compliant)

One time soldering reflow is recommended within the condition of temperature and time profile shown below. Do not solder more than three times.

Profile item	Conditions
Preheat	
- Temperature Min (T_{Smin})	150˚C
- Temperature Max (T_{Smax})	200˚C
- Time (min to max) (ts)	90±30 sec
Soldering zone	
- Temperature (T_L)	217˚C
- Time (t_L)	60 sec
Peak Temperature (T_P)	260˚C
Ramp-up rate	3˚C / sec max.
Ramp-down rate	3~6˚C / sec



6.2 Wave soldering (JEDEC22A111 compliant)

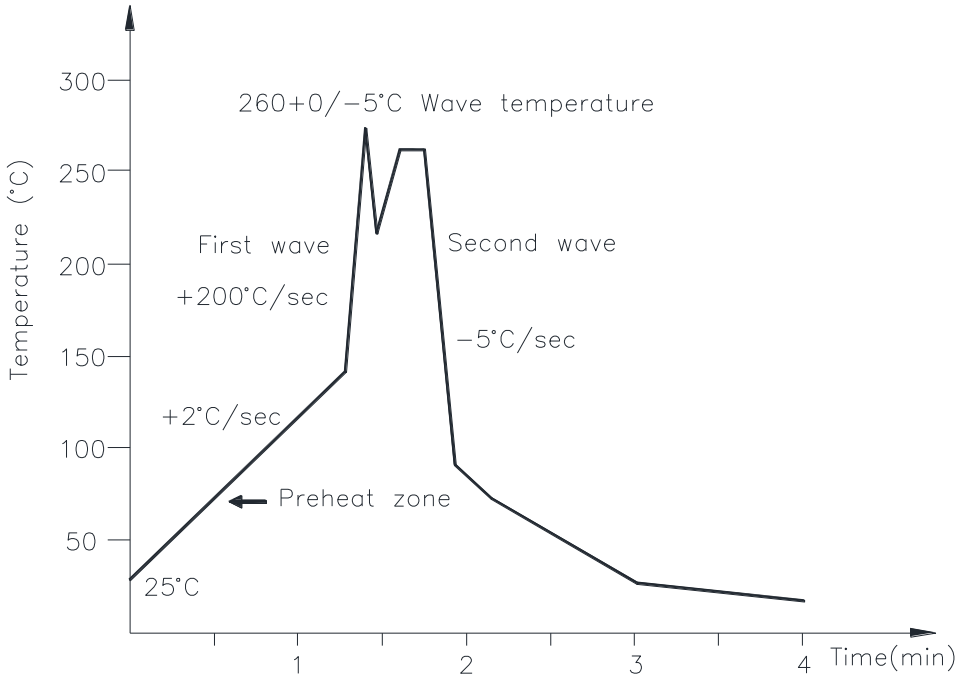
One time soldering is recommended within the condition of temperature.

Temperature: 260+0/-5˚C

Time: 10 sec.

Preheat temperature:25 to 140˚C

Preheat time: 30 to 80 sec.



6.3 Hand soldering by soldering iron

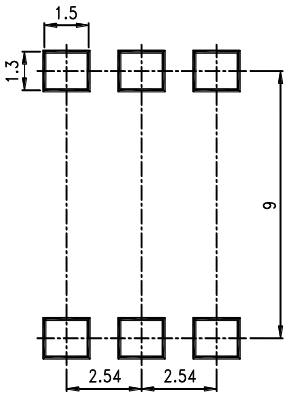
Allow single lead soldering in every single process. One time soldering is recommended.

Temperature: 380+0/-5˚C

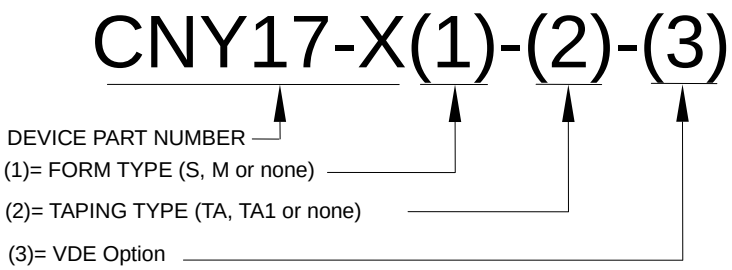
Time: 3 sec max.

7. RRECOMMENDED FOOT PRINT PATTERNS (MOUNT PAD)

Unit: mm



8. NAMING RULE



9. Notes:

- LiteOn is continually improving the quality, reliability, function or design and LiteOn reserves the right to make changes without further notices.
- The products shown in this publication are designed for the general use in electronic applications such as office automation equipment, communications devices, audio/visual equipment, electrical application and instrumentation.
- For equipment/devices where high reliability or safety is required, such as space applications, nuclear power control equipment, medical equipment, etc, please contact our sales representatives.
- When requiring a device for any “specific” application, please contact our sales in advice.
- If there are any questions about the contents of this publication, please contact us at your convenience.
- The contents described herein are subject to change without prior notice.
- Immerge unit’s body in solder paste is not recommended.